
Chiral symmetry breaking and the Quantum Hall effect in monolayer graphene

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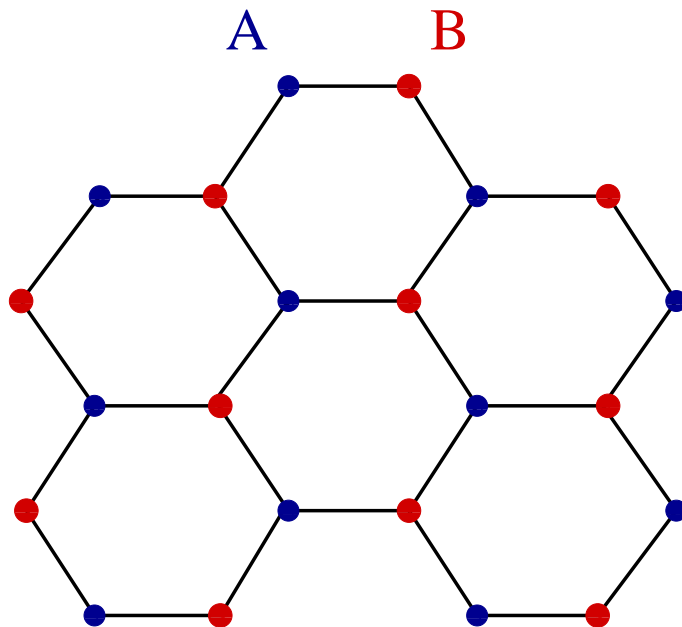
B. Roy, M. K., and S. Das Sarma, Phys. Rev. B 90, 201409(R) (2014).

Motivation and Summary

- Integer Quantum Hall states are observed at fillings $\nu = 0$ and $\nu = \pm 1$ in graphene that cannot be explained within a picture of non-interacting electrons: **unexpected fillings and gap too large to be Zeeman splitting**
- We suggest that in a magnetic field, electron-electron interactions can induce ordered phases via “**magnetic catalysis**”. The order parameters correspond to chiral (sublattice) symmetry breaking Dirac masses, leading to formation of gaps for $\nu = 0, \pm 1$
 - $\nu = 0$: **Coexisting easy-plane Neel order and easy-axis ferromagnetism**
 - $\nu = \pm 1$: **Coexisting charge density wave and easy-axis Neel order**
- We calculate gaps for these orders and find good agreement with experiment for both $\nu = 0$ and $\nu = \pm 1$

Graphene

- Two triangular sublattices:
A and B
- One electron per site: half filling



- Tight binding model (Wallace, 1947)
nearest neighbour hopping
($t = 2.5 \text{ eV}$)

$$H_0 = -t \sum_{\mathbf{r}_i, j, \sigma} [u_{\sigma}^{\dagger}(\mathbf{r}_i) v_{\sigma}(\mathbf{r}_i + \mathbf{a}_j) + h.c.]$$

- Energy Spectrum

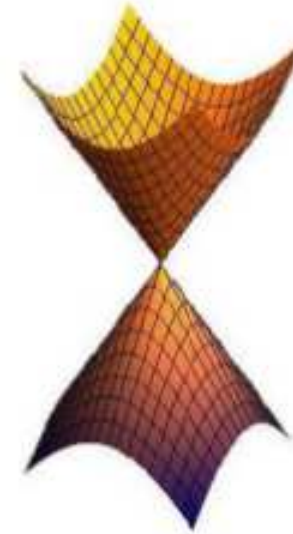
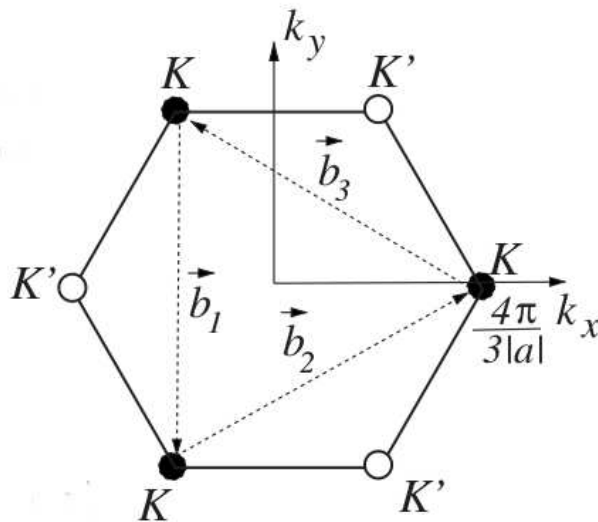
$$E(\mathbf{k}) = \pm t \left| \sum_j e^{i\mathbf{k} \cdot \mathbf{a}_j} \right|$$

\mathbf{a}_j : nearest neighbour separations

- Lack of inversion symmetry around each site
 \implies Fermi points rather than a Fermi surface (unlike square lattice)

Emergent Dirac fermions

- Dirac cones centered on two inequivalent Dirac points: K and K'



- Low energy theory: Dirac Hamiltonian for 8 component Dirac fermions (2 spin, 2 valley, 2 sublattice)

$$H = \sigma_0 \otimes H_0, \quad H_0 = \sum_{j=1}^2 i\gamma_0\gamma_j (-i\partial_j - A_j)$$

- Gamma matrices $\{\gamma_\mu, \gamma_\nu\} = 2\delta_{\mu\nu}$, units with $e, \hbar, v_F = 1$ ($v_F \sim c/300$)
- Emergent chiral symmetry (for spinless fermions) under SU(2) generators

$$\{\gamma_3, \gamma_5, i\gamma_3\gamma_5\}$$

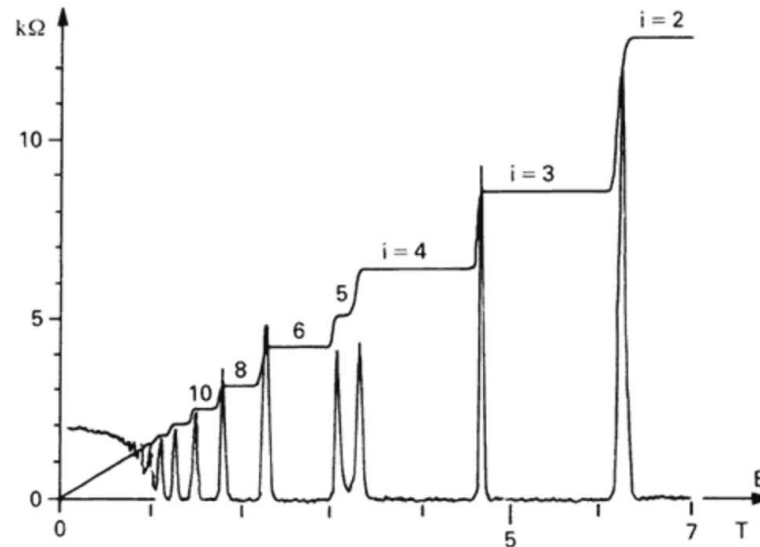
generator of translations: $i\gamma_3\gamma_5 = \tau_3 \otimes s_0$

(σ : spin, τ : valley pseudospin, s : sublattice pseudospin)

Integer Quantum Hall Effect

- Quantized Hall conductance

$$\sigma_{xy} = \nu \frac{e^2}{h}$$



Resistance vs field: GaAs [www.nobelprize.org]

- Landau levels

$$E_n = \hbar\omega_c \left(n + \frac{1}{2} \right)$$

- Degeneracy

$$eBA/h = \Phi/\Phi_0$$

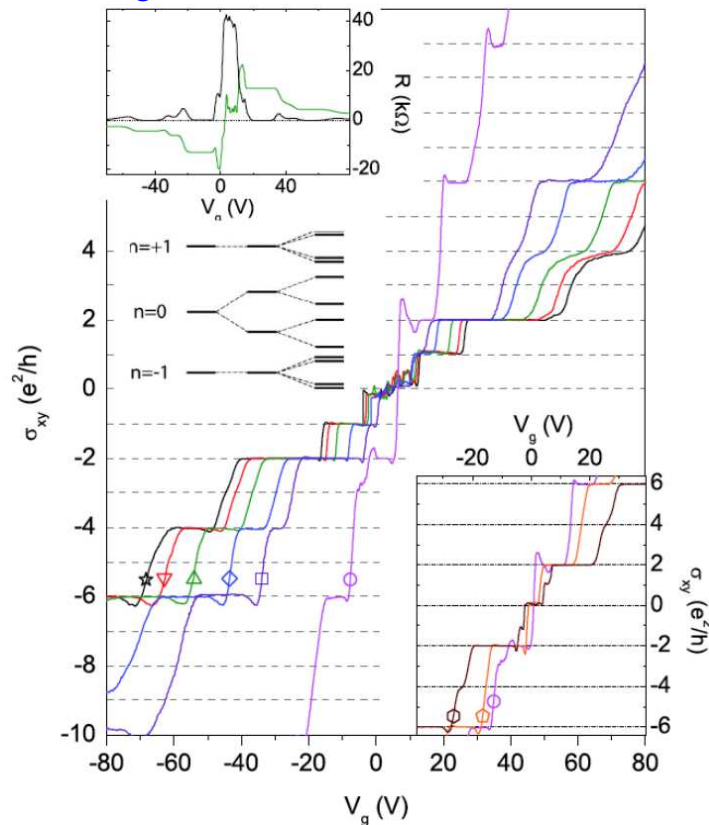
Integer QHE in Graphene

- Dirac fermions in a magnetic field: relativistic Landau levels:

$$E_n = \pm\sqrt{2nB}, \quad n = 0, 1, 2, \dots$$

- Experiment:

Y. Zhang *et al.*, PRL 2006



- Weak magnetic fields:

$$\nu = \pm(4n + 2) \text{ for } n = 1, 2, \dots$$

Degeneracy:

$$2 \text{ (valley)} \times 2 \text{ (spin)} \times \Phi/\Phi_0$$

Gusynin and Sharapov, PRL 2005

- Strong magnetic fields

– additional plateaux:

i) $\nu = 0, \pm 1$

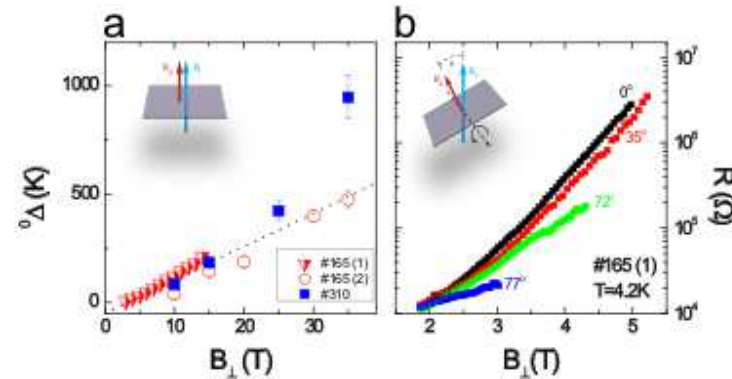
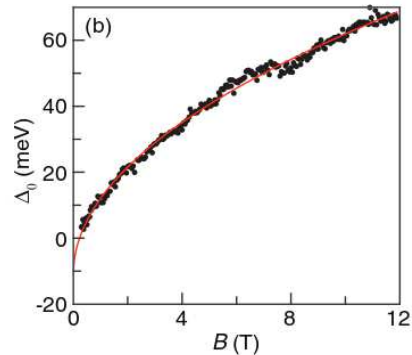
\implies Interaction driven symmetry breaking

ii) $\nu = \pm 4, \dots$

Zeeman splitting of higher LLs

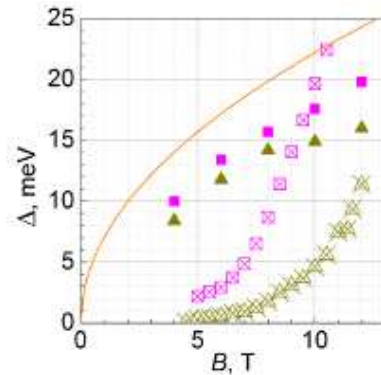
Gap for the $\nu = 0$ Hall state

Different groups techniques/substrates



Compressibility/suspended

Abanin et al, PRB 88, 115407 (2013)



Capacitance/ boron nitride

Yu et al., PNAS 110, 3282 (2013)

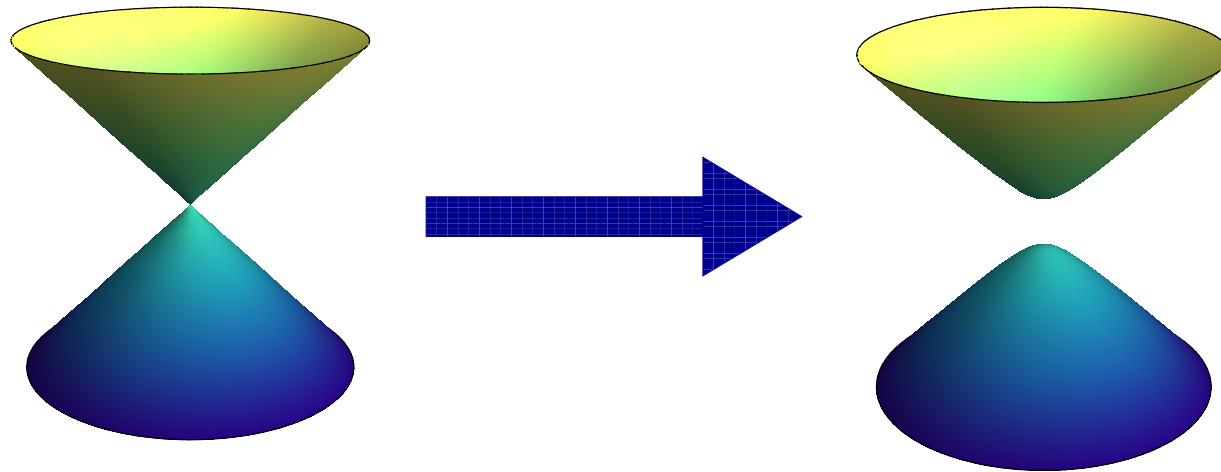
Transport/ boron nitride

Young et al., Nat. Phys. 8, 550 (2012)

- Gap for $\nu = 0$ Hall state shows crossover from linear to $\sim \sqrt{B}$ sub-linear dependence on magnetic field
- Resistance (R_{xx}) decreases with tilting of magnetic field (increasing B_{\parallel} at fixed total field)

Interactions and symmetry breaking orders

- No magnetic field: strong interactions \implies Dirac fermion masses



- Short range electron-electron interactions: Hubbard U , V_1 , V_2
- Order parameter Δ

$$\epsilon_{\pm}(\mathbf{p}) = \pm \sqrt{|p|^2 + |\Delta|^2}$$

Chiral symmetry breaking orders

CSB orders – break sublattice symmetry

$$H_{CSB} = \sigma_0 \otimes H_0 + m_j(\sigma_j \otimes \gamma_0), \quad \gamma_0 = \tau_0 \otimes s_3$$

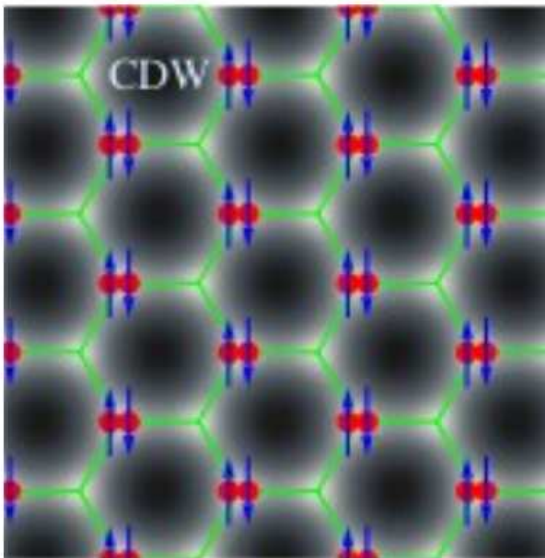
Antiferromagnetism ($j = 1, 2, 3$): Hubbard repulsion U

[I. Herbut, PRL 2006, Assaad and Herbut, PRX 2013]

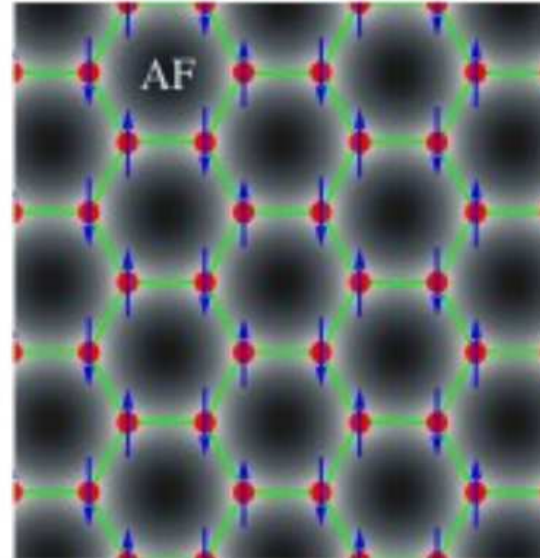
Charge density wave ($j = 0$): Nearest-neighbour repulsion V_1

[Herbut, PRL 2006; Herbut *et al*, PRB 2009; Weeks and Franz, PRB 2010]

Charge density wave



Antiferromagnetism



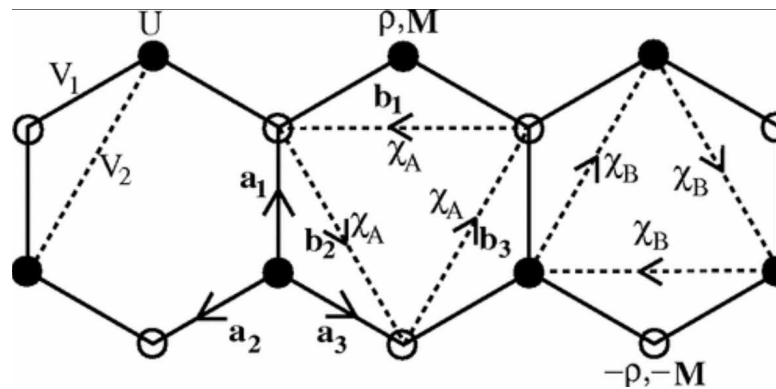
Topological orders

Broken time reversal symmetry

$$H_{TRSB} = \sigma_0 \otimes H_0 + \tilde{m}_j(\sigma_j \otimes i\gamma_1\gamma_2)$$

Quantum Anomalous Hall ($j = 0$)/ Spin Hall ($j = 1, 2, 3$) Insulators:
Next nearest-neighbour interactions V_2

[Raghu *et al.*, PRL 2008; Roy and Herbut, PRB 2013]

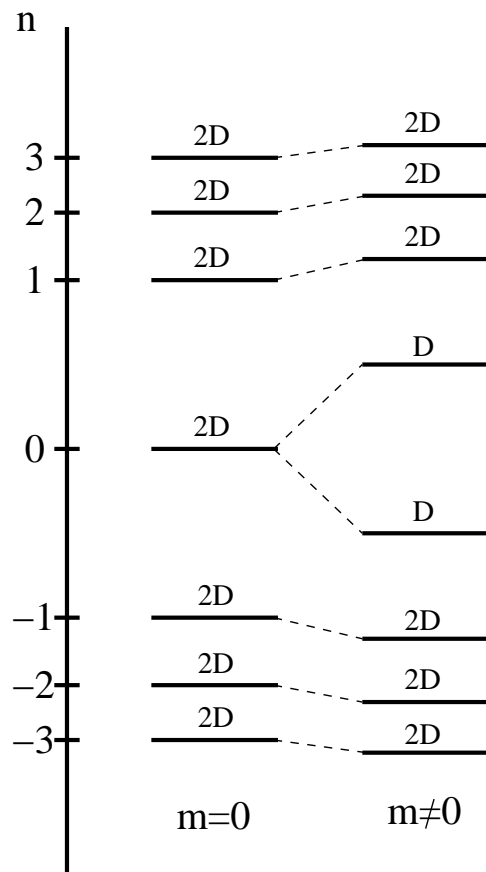


[Raghu *et al.*, PRL 2008]

- In graphene: $U_{\text{crit}} > U > V_1 > V_2$ [Wehling *et al.*, PRL 106, 236805 (2011)]
 - Interactions not strong enough to generate CSB orders when $B = 0$
- Magnetic fields can help CSB ordering at weak coupling

Magnetic Catalysis

- Magnetic fields quench kinetic energy \implies enhances interactions
- Formation of CSB orders at infinitesimal interaction in a magnetic field



Degeneracy $D = B/2\pi$

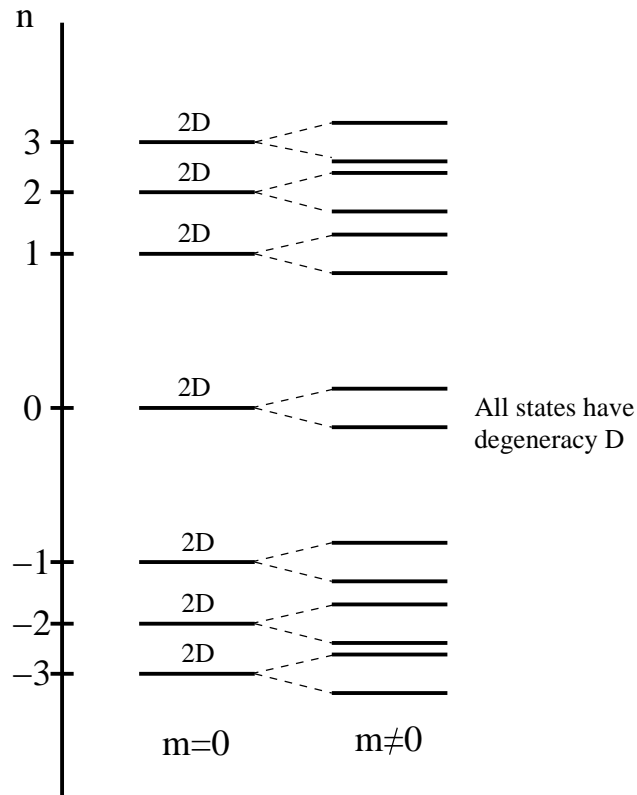
- Zeroth LL simultaneously sublattice/valley polarized
- Weak $U, V_1 \implies$ AFM, CDW
[I. Herbut, PRB 2007]
- Magnetic catalysis: magnetic field allows formation of CSB orders for subcritical zero field coupling
[V. P. Gusynin *et al.*, PRL 73, 3499 (1994)]
- Splits ZLL, pushes down **all** filled LLs
 $\implies \nu = 0$ state

Filled LL with CSB order:

$$E_n = -\sqrt{2nB + \Delta_{CSB}^2}$$

Other proposals

- Quantum Hall Ferromagnetism



- QHF: breaks valley degeneracy (sublattice symmetry not broken)
[Barlas *et al.*, Nanotechnology (2012)]

$$\sigma_0(\text{spin}) \otimes \tau_3(\text{valley}) \otimes s_0(\text{sublattice})$$

- Splits all filled Landau levels:

$$E = -\sqrt{2nB} \pm \Delta_{QHF}$$

- Gains energy only by splitting ZLL c.f. CSB masses – all LLs contribute

- Long range Coulomb interaction

Gap $\sim \sqrt{B}$: does not capture crossover in gap dependence on B_{\perp}

Self-consistent theory of $\nu = 0$ Hall state

- On-site repulsion \implies antiferromagnetism (CSB Dirac mass)
- Magnetic field: Zeeman coupling (λ) \implies ferromagnetism

Dirac LLs $\pm E_{n,\sigma}$:

$$E_{n\sigma} = \sqrt{N_{\perp}^2 + \left[\sqrt{N_3^2 + 2nB} + \sigma(m + \lambda) \right]^2}$$

Non-zero $\lambda \implies N_3 = 0$: Easy-plane antiferromagnet

AFM order $\perp B$, FM order $\parallel B$ [I. Herbut, PRB 76, 085432 (2007)]

- Free energy: in-plane antiferromagnetism (N_{\perp}) and ferromagnetism (m)

$$F_0 = \frac{N_{\perp}^2}{4g_a} + \frac{m^2}{4g_f} - D \sum_{\sigma=\pm} \left[\frac{1}{2} E_{0,\sigma} + \sum_{n \geq 1} E_{n,\sigma} \right]$$

Gap equations

Minimize F_0 with respect to N_{\perp} and m :

$$\frac{1}{g_a} = \frac{B}{\pi} \sum_{\sigma=\pm} \left[\frac{1}{2E_{0,\sigma}} + \sum_{n \geq 1}^{N_{\max}} \frac{1}{E_{n,\sigma}} \right],$$

Displays UV divergence as $N_{\max} \rightarrow \infty$ (filled LLs pushed down)

$$\frac{1}{g_f} = \frac{B}{\pi} \sum_{\sigma=\pm} \left[\frac{(m + \lambda)}{2E_{0,\sigma}} + \sum_{n \geq 1}^{N_{\max}} \frac{(m + \lambda) + \sigma \sqrt{2nB}}{E_{n,\sigma}} \right].$$

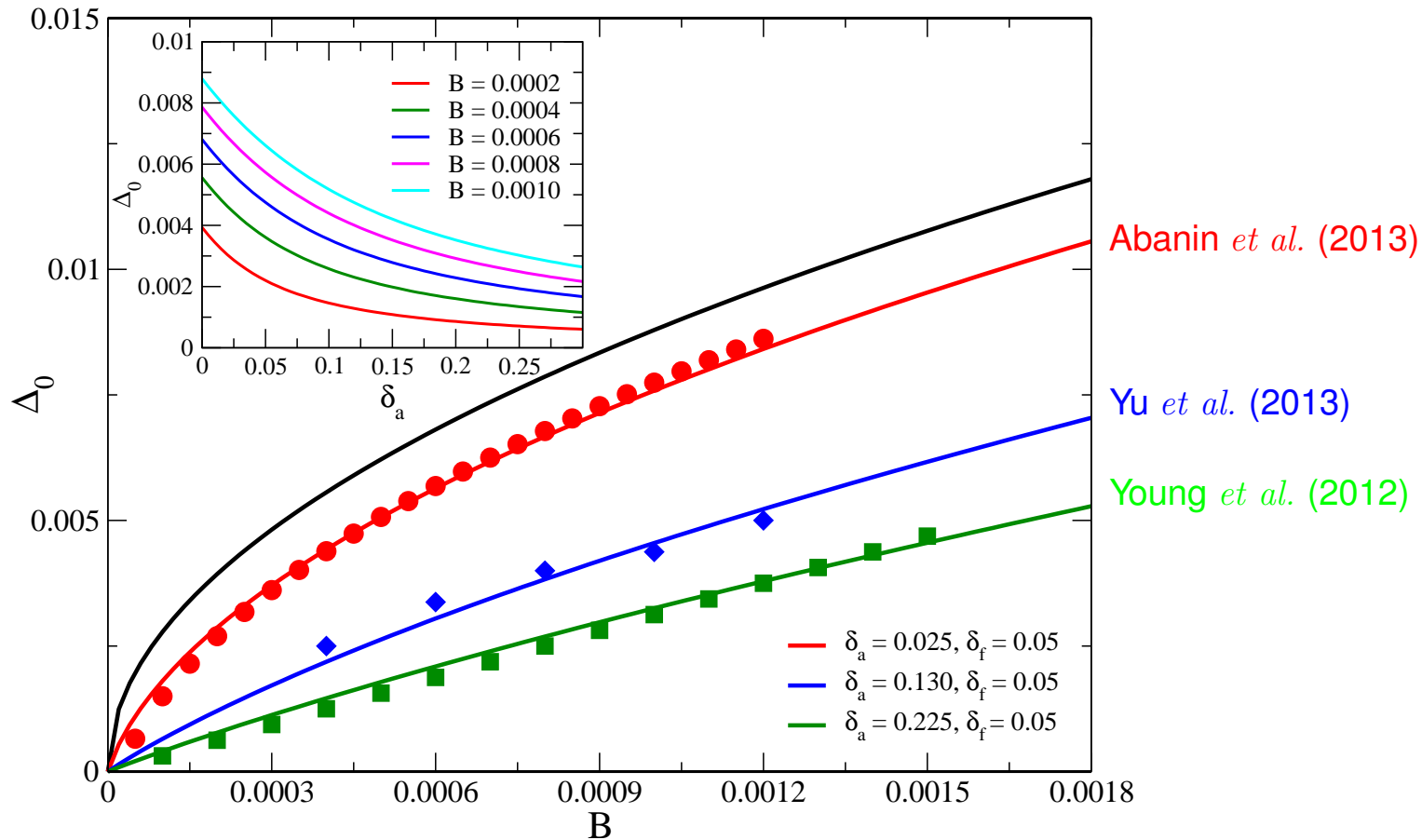
No UV divergence (filled LLs are split)

- Regularization: $\delta_a = \pi \left[\frac{1}{g_a \Lambda} - \frac{1}{g_a^c \Lambda} \right]$ with $(g_a^c)^{-1} = \int_{\Lambda^{-1}}^{\infty} ds/s^{\frac{3}{2}}$

δ_a measures distance from zero field AFM quantum critical point g_a^c

$\delta_a > 0$: subcritical interaction

Comparison with experiments at $\nu = 0$

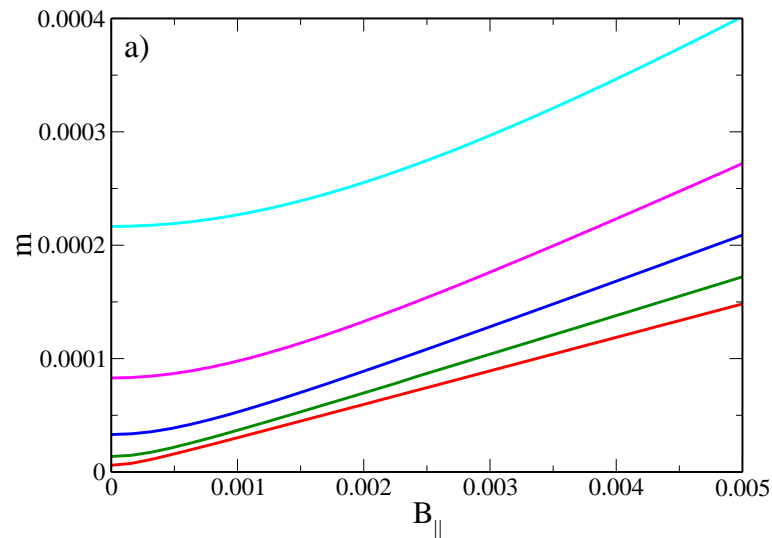


- Two parameter fits to gap for easy plane antiferromagnetic (N_\perp) order. Ferromagnetism $m \ll N_\perp$.
- Single parameter fits (with $\delta_f = 0, m = 0$) are equally good – keep m for consistency

$\nu = 0$ Hall state in tilted magnetic fields

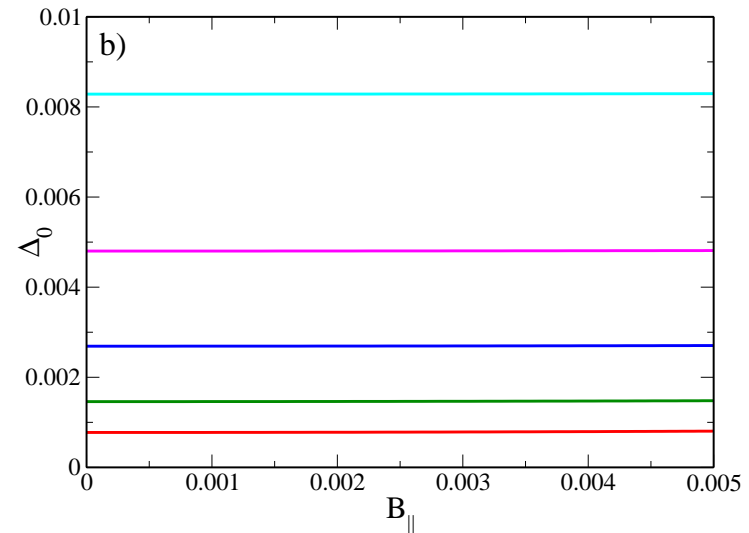
- N_{\perp} and m scale with B_{\perp} (Dirac LL driven orderings)
- Zeeman coupling λ scales with total magnetic field B_T not B_{\perp}

Ferromagnetic order, m , and gap Δ for $0 \lesssim B_{\parallel} \lesssim 50$ T at fixed B_{\perp}



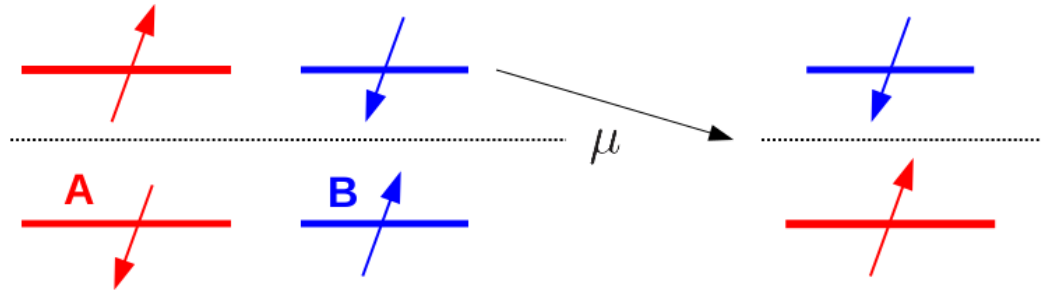
$$B_{\perp} = 2, 4, 8, 16, 32 \text{ T}$$

m grows linearly with B_{\parallel} for $B_{\parallel} \gtrsim 2$ T



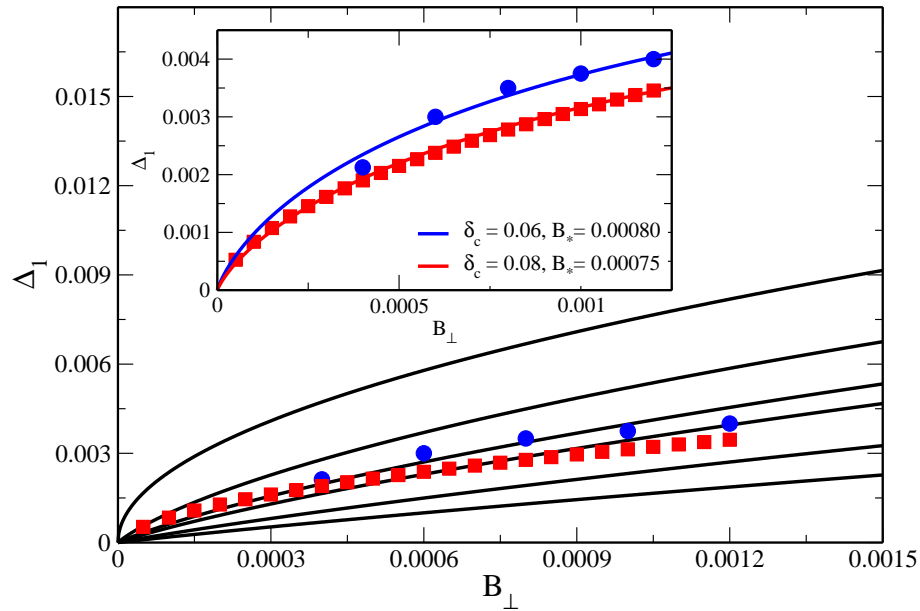
QHE at $\nu = \pm 1$

- Chemical potential close to first excited state



- Simultaneous lifting of sublattice and staggered spin degeneracy
- Lifting of sublattice degeneracy \implies charge density wave (CDW)
 \implies charge gap $\Delta_1^C = C$ (scales with B_\perp)
- Lifting of staggered spin degeneracy \implies easy axis AFM (N_3)
 \implies spin gap $\Delta_1^S \propto (\lambda + m)$
- Coexistence of two chiral symmetry breaking orders
- $C \sim V_1$ (nearest-neighbour repulsion), hence $C \gg m + \lambda$, and $\Delta_1^C \gg \Delta_1^S$
– gap in $\nu = \pm 1$ state primarily from C (CDW)

Comparison with experiments for $\nu = 1$



Yu *et al.* (2013)

Abanin *et al.* (2013)

- Self-consistent calculation of CDW gap similar to AFM gap for $\nu = 0$
- Long-range Coulomb interactions renormalize Fermi velocity

$$v_F = v_F^0 \left[1 + \frac{e^2}{8\epsilon v_F} \ln \left(\frac{B^*}{B} \right) \right]$$

where v_F^0 is the bare Fermi velocity, $B^* \sim 8$ T

[Theory: Herbut and Roy, PRB (2008); Experiment: Faugeras *et al.*, PRL (2015)]

\implies renormalizes $\nu = 1$ gap (in units of $v_F \Lambda$)

Summary

- Scenario for formation of gaps for $\nu = 0$: formation of CSB Dirac masses via [magnetic catalysis](#)
 - Microscopic origin: weak short range interactions
 - Candidate orders: Antiferromagnetism, CDW
- Observed scaling behaviour of the gap for $\nu = 0$ with magnetic field including both linear and sublinear ($\sim \sqrt{B}$) regimes can be explained with easy plane antiferromagnetism coexisting with weak easy-axis ferromagnetism
- The scaling of the gaps in the $\nu = 1$ state can be explained within the same framework: dominant CDW with weak easy axis antiferromagnetism
- A similar mechanism can be applied to other graphene-based layered systems, e.g. bilayer and trilayer graphene [[B. Roy, PRB 2014](#)] , Weyl semimetals [[B. Roy, arXiv:1406.4501](#)]
- Implications for Fractional Quantum Hall states?

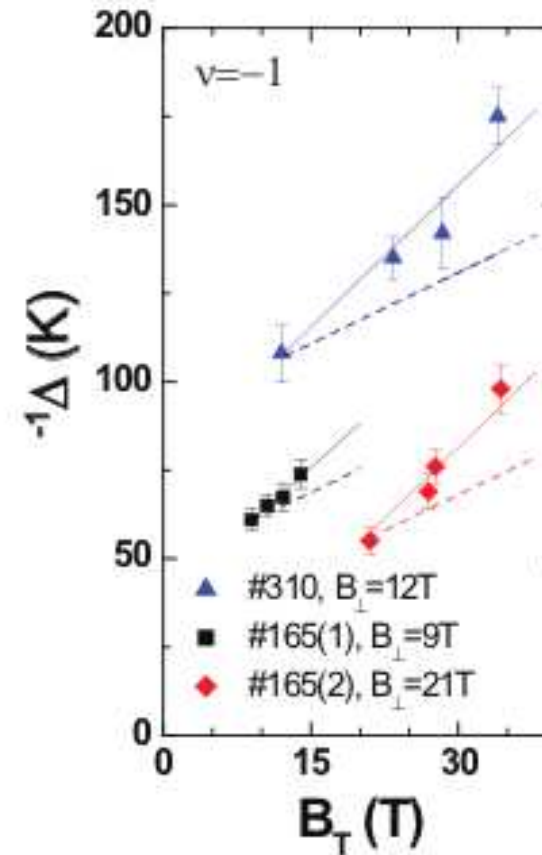
[B. Roy, M. K., and S. Das Sarma, Phys. Rev. B 90, 201409\(R\) \(2014\).](#)

$\nu = 1$ Hall state in a tilted magnetic field

- Excitation gap
(charge and spin contributions)

$$\Delta_1 \simeq \Delta_1^C + \Delta_1^S,$$

- Charge gap $\Delta_1^C = C$ (scales as B_\perp)
- Spin gap $\Delta_1^S = 2(m + \lambda)N_3/\Delta_0$
 - N_3, Δ_0 scale as B_\perp
 - $(m + \lambda)$ scales as B_T
- Experimentally, gap scales with B_T but with larger slope than for single particle Zeeman coupling (λ):
presence of a spin gap provides an explanation for the enhanced slope



Young, *et al.*, Nat. Phys. (2012).